1-Bit Dual-Supply **Non-Inverting Level Translator**

The NLSV1T244 is a 1-bit configurable dual-supply voltage level translator. The input A_n and output B_n ports are designed to track two different power supply rails, V_{CCA} and V_{CCB} respectively. Both supply rails are configurable from 0.9 V to 4.5 V allowing universal low-voltage translation from the input A_n to the output B_n port.

Features

- Wide V_{CCA} and V_{CCB} Operating Range: 0.9 V to 4.5 V
- High-Speed w/ Balanced Propagation Delay
- Inputs and Outputs have OVT Protection to 4.5 V
- Non-preferential V_{CCA} and V_{CCB} Sequencing
- Outputs at 3-State until Active V_{CC} is Reached
- Power-Off Protection
- Outputs Switch to 3-State with V_{CCB} at GND
- Ultra-Small Packaging: 1.2 mm x 1.0 mm UDFN6
- NLVSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- FATIVE FOR INF • These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS

Typical Applications

• Mobile Phones, PDAs, Other Portable Devices

Important Information

• ESD Protection for All Pins: HBM (Human Body Model) > 3000

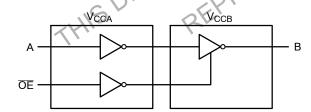
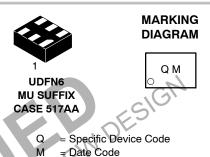


Figure 1. Logic Diagram

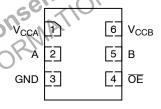


ON Semiconductor®

www.onsemi.com



PIN ASSIGNMENT



(Top View)

ORDERING INFORMATION

Device	Package	Shipping [†]
NLSV1T244MUTBG,	UDFN6	3000 / Tape &
NLVSV1T244MUTBG	(Pb-Free)	Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

PIN ASSIGNMENT

PIN	FUNCTION
V _{CCA}	Input Port DC Power Supply
V _{CCB}	Output Port DC Power Supply
GND	Ground
А	Input Port
В	Output Port
ŌĒ	Output Enable

TRUTH TABLE

In	Outputs	
ŌĒ	Α	В
L	L	L
L	Н	Н
Н	X	3-State

MAXIMUM RATINGS

Symbol	Rating	Value	Condition	Unit
V _{CCA} , V _{CCB}	DC Supply Voltage	-0.5 to +5.5		V
V _I	DC Input Voltage A	-0.5 to +5.5		V
V _C	Control Input OE	-0.5 to +5.5	CIGI.	V
Vo	DC Output Voltage (Power Down) B	-0.5 to +5.5	$V_{CCA} = V_{CCB} = 0$	V
	(Active Mode) B	-0.5 to +5.5		V
	(Tri-State Mode) B	-0.5 to +5.5	NEV.	V
I _{IK}	DC Input Diode Current	-20	V _I < GND	mA
lok	DC Output Diode Current	-50	V _O < GND	mA
I _O	DC Output Source/Sink Current	±50	30/1/0	mA
I _{CCA} , I _{CCB}	DC Supply Current Per Supply Pin	±100	W.	mA
I _{GND}	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V _{CCA} , V _{CCB}	Positive DC Supply Voltage		0.9	4.5	V
VI	Bus Input Voltage		GND	4.5	٧
V _C	Control Input	ŌĒ	GND	4.5	٧
V _{IO}	Bus Output Voltage (Power Down Mode)	В	GND	4.5	٧
141.	(Active Mode)	В	GND	V _{CCB}	٧
	(Tri-State Mode)	В	GND	4.5	٧
T _A	Operating Temperature Range		-40	+85	°C
Δt / ΔV	Input Transition Rise or Rate V_{I} , from 30% to 70% of V_{CC} ; V_{CC} = 3.3 V ±0.3 V		0	10	nS

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

					-40°C to	o +85°C	
Symbol	Parameter	Test Conditions	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Uni
V _{IH}	Input HIGH Voltage		3.6 – 4.5	0.9 – 4.5	2.2	_	V
	(A, OE)		2.7 – 3.6		2.0	-	
			2.3 – 2.7		1.6	-	
			1.4 – 2.3		0.65 * V _{CCA}	-	
			0.9 – 1.4		0.9 * V _{CCA}	-	
V _{IL}	Input LOW Voltage		3.6 – 4.5	0.9 – 4.5	_	0.8	V
	(A, OE)		2.7 – 3.6		-	0.8	
			2.3 – 2.7		_	0.7	
			1.4 – 2.3		-	0.35 * V _{CCA}	
			0.9 – 1.4		-	0.1 * V _{CCA}	
V _{OH}	Output HIGH Voltage	$I_{OH} = -100 \mu A; V_I = V_{IH}$	0.9 – 4.5	0.9 – 4.5	V _{CCB} - 0.2	No	V
		$I_{OH} = -0.5 \text{ mA}; V_I = V_{IH}$	0.9	0.9	0.75 * V _{CCB}	SI	
		$I_{OH} = -2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	1.05	/ -	
		$I_{OH} = -6 \text{ mA}; V_I = V_{IH}$	1.65	1.65	1,25	_	
			2.3	2.3	2.0	_	
		$I_{OH} = -12 \text{ mA}; V_I = V_{IH}$	2.3	2.3	1.8	_	
			2.7	2.7	2.2	_	
		$I_{OH} = -18 \text{ mA}; V_I = V_{IH}$	2.3	2.3	1.7	-	
			3.0	3.0	2.4	=	
		$I_{OH} = -24 \text{ mA}; V_l = V_{lH}$	3.0	3.0	2.2	_	
V _{OL}	Output LOW Voltage	$I_{OL} = 100 \mu A; V_I = V_{IL}$	0.9 – 4.5	0.9 – 4.5	-	0.2	V
		$I_{OL} = 0.5 \text{ mA}; V_I = V_{IL}$	1,12	1.1	-	0.3	
		$I_{OL} = 2 \text{ mA}; V_I = V_{IL}$	1.4	1.4	-	0.35	
	15	$I_{OL} = 6 \text{ mA}; V_I = V_{IL}$	1.65	1.65	-	0.3	
	A PIC	$I_{OL} = 12 \text{ mA}; V_I = V_{IL}$	2.3	2.3	-	0.4	
	19.19	SV KK	2.7	2.7	-	0.4	
	"CE JER	$I_{OL} = 18 \text{ mA}; V_I = V_{IL}$	2.3	2.3	-	0.6	
	EVICE		3.0	3.0	-	0.4	
	O S PLEA S DEVICE PLEA S DEPRE	I_{OL} = 24 mA; V_I = V_{IL}	3.0	3.0	-	0.55	
l _l	Input Leakage Current	$V_I = V_{CCA}$ or GND	0.9 – 4.5	0.9 – 4.5	-1.0	1.0	μΑ
l _{OFF}	Power-Off Leakage Current	<u>OE</u> = 0 V	0 0.9 – 4.5	0.9 – 4.5 0	-1.0 -1.0	1.0 1.0	μΑ
I _{CCA}	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$, $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	-	1.0	μΑ
I _{CCB}	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$, $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	-	1.0	μΔ
CA + ICCB	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$, $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	-	2.0	μÆ
ΔI_{CCA}	Increase in I _{CC} per Input Voltage, Other Inputs at V _{CCA} or GND	$V_I = V_{CCA} - 0.6 \text{ V};$ $V_I = V_{CCA} \text{ or GND}$	4.5 3.6	4.5 3.6	-	10 5.0	μA
ΔI_{CCB}	Increase in I _{CC} per Input Voltage, Other Inputs at V _{CCA} or GND	$V_I = V_{CCA} - 0.6 \text{ V};$ $V_I = V_{CCA} \text{ or GND}$	4.5 3.6	4.5 3.6	-	10 5.0	μA
l _{OZ}	I/O Tri-State Output Leakage Current	$T_A = 25^{\circ}C, \overline{OE} = 0 \text{ V}$	0.9 – 4.5	0.9 – 4.5	-1.0	1.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TOTAL STATIC POWER CONSUMPTION (I_{CCA} + I_{CCB})

· · · · · · · · · · · · · · · · · · ·											
-40°C to +85°C											
	V _{CCB} (V)										
	4.	4.5 3.3 2.8 1.8				0.	.9				
V _{CCA} (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
4.5		2		2		2		2		< 1.5	μΑ
3.3		2		2		2		2		< 1.5	μΑ
2.8		< 2		< 1		< 1		< 0.5		< 0.5	μΑ
1.8		< 1		< 1		< 0.5		< 0.5		< 0.5	μΑ
0.9		< 0.5		< 0.5		< 0.5		< 0.5		< 0.5	μΑ

NOTE: Connect ground before applying supply voltage V_{CCA} or V_{CCB}. This device is designed with the feature that the power–up sequence of V_{CCA} and V_{CCB} will not damage the IC.

AC ELECTRICAL CHARACTERISTICS

							-40°C to	o +85°C				2	
		1					V _{CCI}	₃ (V)	4			101	
			4.	.5	3.	.3	2.	.8	1.	.8	A P	2	
Symbol	Parameter	V _{CCA} (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t _{PLH} ,	Propagation	4.5		1.6		1.8		2.0	1	2.1		2.3	nS
t _{PHL} (Note 1)	Delay,	3.3		1.7		1.9		2.1	R	2.3		2.6	
(Note 1)	A to B	2.8		1.9		2.1		2.3),	2.5	17	2.8	
		1.8		2.1		2.4		2.5	750	2.7)	3.0	
		1.2		2.4		2.7	70 ×	2.8	N	3.0		3.3	
t _{PZH} ,	Output	4.5		2.6		3.8		4.0)/~,	4.1		4.3	nS
t _{PZL}	t _{PZL} Enable, (Note 1)	3.3		3.7	ON	3.9	40,	4.1		4.3		4.6	
(Note 1)		2.5	1	3.9	7	4.1	R	4.3		4.5		4.8	
		1.8		4.1	N	4.4	Ο,	4.5		4.7		5.0	
		1.2	(O)	4.4), (4.7		4.8		5.0		5.3	
t _{PHZ} ,	Output	4.5	76	2.6	17	3.8		4.0		4.1		4.3	nS
t _{PLZ} (Note 1)	Disable,	3.3	: Do	3.7	,	3.9		4.1		4.3		4.6	
(Note 1)	OE to B	2.5		3.9		4.1		4.3		4.5		4.8	
	OF	1.8	27	4.1		4.4		4.5		4.7		5.0	
	15	1.2		4.4		4.7		4.8		5.0		5.3	
t _{OSHL} ,	Output to	4.5		0.15		0.15		0.15		0.15		0.15	nS
toslh	Output Skew,	3.3		0.15		0.15		0.15		0.15		0.15	
(Note 1)	Tim	2.5		0.15		0.15		0.15		0.15		0.15	
		1.8		0.15		0.15		0.15		0.15		0.15	
		1.2		0.15		0.15		0.15		0.15		0.15	

^{1.} Propagation delays defined per Figure 2.

CAPACITANCE

Symbol	Parameter	Test Conditions	Typ (Note 2)	Unit
C _{IN}	Control Pin Input Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$	3.5	pF
C _{I/O}	I/O Pin Input Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$	5.0	pF
C _{PD}	Power Dissipation Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_{I} = 0 \text{ V or } V_{CCA}, f = 10 \text{ MHz}$	5.0	pF

Typical values are at T_A = +25°C.
 C_{PD} is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: I_{CC(operating)} ≅ C_{PD} x V_{CC} x f_{IN} where I_{CC} = I_{CCA} + I_{CCB}.

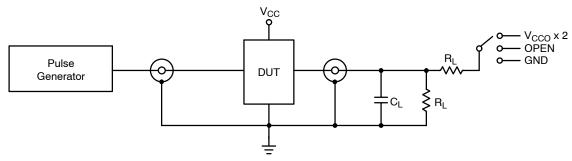


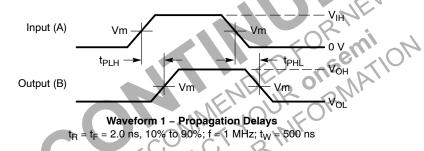
Figure 2. AC (Propagation Delay) Test Circuit

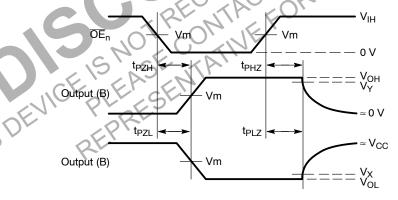
Test	Switch
t _{PLH} , t _{PHL}	OPEN
t_{PLZ} , t_{PZL}	V _{CCO} x 2
t _{PHZ} , t _{PZH}	GND

C_L = 15 pF or equivalent (includes probe and jig capacitance)

 R_L = 2 $k\Omega$ or equivalent

 Z_{OUT} of pulse generator = 50 Ω





Waveform 2 – Output Enable and Disable Times $t_R = t_F = 2.0 \text{ ns}$, 10% to 90%; f = 1 MHz; $t_W = 500 \text{ ns}$

Figure 3. AC (Propagation Delay) Test Circuit Waveforms

	V _{CC}						
Symbol	3.0 V – 4.5 V	2.3 V – 2.7 V	1.65 V – 1.95 V	1.4 V – 1.6 V	0.9 V – 1.3 V		
V_{mA}	V _{CCA} /2						
V _{mB}	V _{CCB} /2						
V _X	V _{OL} x 0.1						
V _Y	V _{OH} x 0.9						



△ aaa C

UDFN6, 1.20x1.00x0.50, 0.40P CASE 517AA ISSUE E

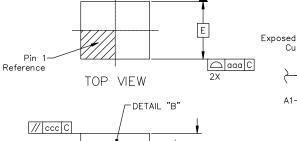
DATE 09 MAY 2025

NOTES:

- 1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018.
- 2. CONTROLLING DIMENSION: MILLIMETERS.

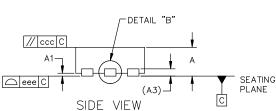
·Mold Compound

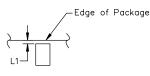
- DIMENSION 6 APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30mm FROM TERMINAL.
- 4. COPLANARITY APPLIES TO TH EXPOSED PAD AS WELL AS THE TERMINALS.



В

D





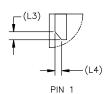
DETAIL "A" Scale 2:1 Bottom View (Optional)

DETAIL "B"

Scale 2:1

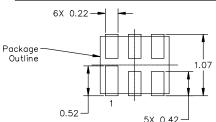
Side View

(Optional)



Chamfer Dimension

MILLIMETERS DIM MIN NOM MAX0.45 0.55 Α 0.50 Α1 0.00 0.05 ____ 0.127 REF А3 0.15 0.20 0.25 b D 1.20 BSC Ε 1.00 BSC 0.40 BSC е 0.30 0.35 0.40 L L1 0.00 ___ 0.15 L2 0.40 0.45 0.50 L3 0.14 REF L4 0.116 REF TOLERANCE FORM & POSITION aaa 0.10 bbb 0.10 CCC 0.10 ddd 0.05 eee 0.08



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb—Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

		/ DI	ETAIL "A"
•	1	3/	•
L2	ЦΨ		5X L
• -	6	4 4 e	T
6X b	-	·	
^Ψ ddd C B(MOTTC	VIEW	

GENERIC MARKING DIAGRAM*				
	VVN4			

XX = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	UDFN6, 1.20x1.00x0.50, 0.40P		PAGE 1 OF 1

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